

Ultrafast 7 ns Single Supply Comparator

AD8561

FEATURES

7 ns Propagation Delay at 5 V Single Supply Operation: 3 V to 10 V Low Power Latch Function TSSOP Packages

APPLICATIONS
High Speed Timing
Clock Recovery and Clock Distribution
Line Receivers
Digital Communications
Phase Detectors
High Speed Sampling
Read Channel Detection
PCMCIA Cards
Upgrade for LT1016 Designs

GENERAL DESCRIPTION

The AD8561 is a single 7 ns comparator with separate input and output sections. Separate supplies enable the input stage to be operated from ±5 V dual supplies and +5 V single supplies.

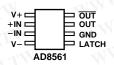
Fast 7 ns propagation delay makes the AD8561 a good choice for timing circuits and line receivers. Propagation delays for rising and falling signals are closely matched and track over temperature. This matched delay makes the AD8561 a good choice for clock recovery, since the duty cycle of the output will match the duty cycle of the input.

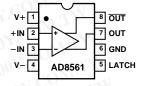
The AD8561 has the same pinout as the LT1016, with lower supply current and a wider common-mode input range, which includes the negative supply rail.

The AD8561 is specified over the industrial (-40°C to +85°C) temperature range. The AD8561 is available in both the 8-lead plastic DIP, 8-lead TSSOP or narrow SO-8 surface mount packages.

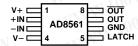
PIN CONFIGURATIONS

8-Lead Narrow Body SO (SO-8) 8-Lead Plastic DIP (N-8)





8-Lead TSSOP (RU-8)



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AD8561-SPECIFICATIONS

ELECTRICAL SPECIFICATIONS (@ V+ = +5.0 V, V- = V_{GND} = 0 V, T_A = +25°C unless otherwise noted)

Parameter	Symbol	Conditions	Min	Тур	Max	Units
INPUT CHARACTERISTICS Offset Voltage	Vos	K.COM.TW WWW.19	oy.co	2.3	7	mV
N. Co. TV	NW 1	$-40^{\circ}\text{C} \le \text{T}_{\text{A}} \le +85^{\circ}\text{C}$			8	mV
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$	COM.	. Vac.	4		μV/°C
Input Bias Current	$I_{\rm B}$	$V_{CM} = 0 \text{ V}$	-6	-3		μA
MAN AND STORY	I_{B}	-40 °C $\leq T_A \leq +85$ °C	-701	-3.5	TW	μA
Input Offset Current	Ios	$V_{CM} = 0 V$	0.0		±4	μΑ
Input Common-Mode Voltage Range	V _{CM}	0.11.6.11.0.11	0.0	0.5	+3.0	V dB
Common-Mode Rejection Ratio	CMRR	$0 \text{ V} \le \text{V}_{\text{CM}} \le +3.0 \text{ V}$	65	85 3000		V/V
Large Signal Voltage Gain Input Capacitance	A _{vo}	$R_L = 10 \text{ k}\Omega$		3.0		pF
input Capacitance	C _{IN}	201100X-COVETY	-1W-1	3.0	OMI	pr
LATCH ENABLE INPUT	W	TOOY.CO. TIN V				
Logic "1" Voltage Threshold	V_{IH}	INN TO COM.	2.0	1.65		V
Logic "0" Voltage Threshold	V_{IL}	1001. OW.I.		1.60	0.8	V
Logic "1" Current	I_{IH}	$V_{LH} = 3.0 \text{ V}$	-1.0	-0.3		μA
Logic "0" Current	I_{IL}	$V_{LL} = 0.3 \text{ V}$	-4	-2		μA
Latch Enable	11	W " 1007. OM.TW		TW.101		VI'T
Pulsewidth	t _{PW(E)}	MAN W. CO. LAN		0		ns
Setup Time	ts	W. 100 COM.		1 2		ns
Hold Time	t _H	NIN 100X. ONLTW	N	1.2	100 x.	ns
DIGITAL OUTPUTS	TW	WWW. ON COM TW				17
Logic "1" Voltage	V_{OH}	$I_{OH} = -50 \mu A, \Delta V_{IN} > 250 \text{ mV}$	3.5			V
Logic "1" Voltage	V_{OH}	$I_{OH} = -3.2 \text{ mA}, \Delta V_{IN} > 250 \text{ mV}$	2.4	3.5		V
Logic "0" Voltage	V _{OL}	$I_{OL} = 3.2 \text{ mA}, \Delta V_{IN} > 250 \text{ mV}$		0.25	0.4	V
DYNAMIC PERFORMANCE	OW.	COM.				A.CO
Propagation Delay	$t_{\rm P}$	200 mV Step with 100 mV Overdrive		6.75	9.8	ns
NWW.	CON	$-40^{\circ}\text{C} \le \text{T}_{\text{A}} \le +85^{\circ}\text{C}$		8	13	ns
Propagation Delay	t _P	100 mV Step with 5 mV Overdrive		8		ns
Differential Propagation Delay	I.V	W 1005.				100 1.
(Rising Propagation Delay vs.	A'COM.	MANN ON COM				LOOY!
Falling Propagation Delay)	$\Delta t_{ m P}$	100 mV Step with 100 mV Overdrive ¹		0.5	2.0	ns
Rise Time	W.Co.	20% to 80%		3.8		ns
Fall Time	CON	80% to 20%	TV.	1.5	WW	ns
POWER SUPPLY	100	W.1. 1. 1. 1. 1. 1. 1. 1. 1. 1. 1. 1. 1.	DIVI	«XI	-111	11.10
Power Supply Rejection Ratio	PSRR	+4.5 V ≤ V+ ≤ +5.5 V	50	65		dB
Positive Supply Current	I+	WWW. AND		4.5	6.0	mA
11 7 " " 1	N.100	$-40^{\circ}\text{C} \le \text{T}_{\text{A}} \le +85^{\circ}\text{C}$			7.5	mA
Ground Supply Current	I_{GND}	$V_0 = 0 \text{ V}, R_L = \infty$		2.2	3.3	mA
-11	W. D.	$-40^{\circ}\text{C} \le \text{T}_{\text{A}} \le +85^{\circ}\text{C}$			3.8	mA
Analog Supply Current	I-100 X	OW.11		2.3	4.5	mA
W.	N 11.	$-40^{\circ}\text{C} \le \text{T}_{\text{A}} \le +85^{\circ}\text{C}$			5.5	mA

NOTES

¹ Guaranteed by design.

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$\textbf{ELECTRICAL SPECIFICATIONS} \ (@V+=+5.0\ V,\ V-=V_{GND}=0\ V,\ V-=-5\ V,\ T_A=+25\ ^{\circ}\text{C unless otherwise noted})$

Parameter	Symbol	Conditions	Min	Typ	Max	Units
INPUT CHARACTERISTICS Offset Voltage	Vos	$-40^{\circ}\text{C} \le \text{T}_{\text{A}} \le +85^{\circ}\text{C}$	COM	TI	7 8	mV mV
Offset Voltage Drift Input Bias Current	$\Delta V_{OS}/\Delta T$ I_{B}	$V_{CM} = 0 \text{ V}$	-6	4 -3	0	μV/°C μA
Input Offset Current Input Common-Mode Voltage Range Common-Mode Rejection Ratio Large Signal Voltage Gain Input Capacitance	$egin{array}{l} I_B & & & & & & & & & & & & & & & & & & &$	$-40^{\circ}\text{C} \le \text{T}_{\text{A}} \le +85^{\circ}\text{C}$ $\text{V}_{\text{CM}} = 0 \text{ V}$ $-5.0 \text{ V} \le \text{V}_{\text{CM}} \le +3.0 \text{ V}$ $\text{R}_{\text{L}} = 10 \text{ k}\Omega$	-7 -5.0 65	-2.5 85 3000 3.0	±4 +3.0	μΑ μΑ V dB V/V pF
LATCH ENABLE INPUT		TOUX COMPLETE WAY				
Logic "1" Voltage Threshold	V_{IH}	1.10° V.COM.	2.0	1.65	Wie	V
Logic "0" Voltage Threshold	V_{IL}	V = 2 0 V	W.10	1.60	0.8	V
Logic "1" Current Logic "0" Current Latch Enable	I_{IH} I_{IL}	$V_{LH} = 3.0 \text{ V}$ $V_{LL} = 0.3 \text{ V}$	-1 -4	-0.5 -2	20 20	μA μA
Pulsewidth	$t_{PW(E)}$	MM.Ing COM.		6		ns
Setup Time	t_S	W.1001. COM.11		1.0		ns
Hold Time	t _H	TW TOOY COMETY	MAN	1.2	- CON	ns
DIGITAL OUTPUTS	VI.	WWW.	WW	1100		W.T.W
Logic "1" Voltage	V_{OH}	$I_{OH} = -3.2 \text{ mA}$	2.6	3.5	NA CU	V
Logic "0" Voltage	V _{OL}	$I_{OL} = 3.2 \text{ mA}$	- 1	0.2	0.3	V
DYNAMIC PERFORMANCE Propagation Delay	$t_{ m P}$	200 mV Step with 100 mV Overdrive		6.5	9.8	ns
		$-40^{\circ}\text{C} \le \text{T}_{\text{A}} \le +85^{\circ}\text{C}$		8	13	ns
Propagation Delay Differential Propagation Delay (Rising Propagation Delay vs.	t _P	100 mV Step with 5 mV Overdrive		\7\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\		ns
Falling Propagation Delay)	$\Delta t_{ m P}$	100 mV Step with 100 mV Overdrive ¹		0.5	2	ns
Rise Time	COMITY	20% to 80%		3.8		ns
Fall Time		80% to 20%		1.5		ns
Dispersion	1 COMP.	ON WWW. COM	TW	1	M. V.	ns
POWER SUPPLY		AN ANN. IOC COM				· VOO.
Power Supply Rejection Ratio Supply Current	PSRR	$\pm 4.5 \text{ V} \le \text{V}_{\text{CC}} \text{ and } \text{V}_{\text{EE}} \le \pm 5.5 \text{ V}$ $\text{V}_{\text{O}} = 0 \text{ V}, \text{R}_{\text{L}} = \infty$	55	70		dB
Positive Supply Current	I+ CON	WALL TO THE TOTAL CO.		4.7	6.5	mA
	1001.	$-40^{\circ}\text{C} \le \text{T}_{\text{A}} \le +85^{\circ}\text{C}$			7.5	mA
Ground Supply Current	$\mathbf{I}_{ ext{GND}}$			2.2		mA
Nagativa Supply Current	LIVE CO	$-40^{\circ}\text{C} \le 1_{\text{A}} \le +85^{\circ}\text{C}$		2.4		mA mA
regative Supply Current	N.700 1.	$-40^{\circ}\text{C} < \text{T}_{\lambda} < +85^{\circ}\text{C}$		2.4		mA
Ground Supply Current Negative Supply Current	I _{GND}	$V_{O} = 0 \text{ V}, R_{L} = \infty$ $-40^{\circ}\text{C} \le T_{A} \le +85^{\circ}\text{C}$ $-40^{\circ}\text{C} \le T_{A} \le +85^{\circ}\text{C}$	COM.T	2.2	3.3 3.8 4.5 5.5	

NOTES

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ELECTRICAL SPECIFICATIONS (@ V+ = +3.0 V, $V- = V_{GND} = 0 \text{ V}$, $T_A = +25 ^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
INPUT CHARACTERISTICS	MMilan	COM.	N.CO	Ar.		
Offset Voltage	Vos	COM:I			7	mV
Input Bias Current	I_{B}	$V_{CM} = 0 V$	-6	-3.0		μA
M. Jan COM.	I_B	$-40^{\circ}\text{C} \le \text{T}_{\text{A}} \le +85^{\circ}\text{C}$	-7	-4		μA
Input Common-Mode Voltage Range	V_{CM}	001. ON 111	0		+1.5	V
Common-Mode Rejection Ratio	CMRR	$0.1 \text{ V} \le \text{V}_{\text{CM}} \le 1.5 \text{ V}$	60		TW	dB
OUTPUT CHARACTERISTICS		TO NO. TWO				
Output High Voltage	V_{OH}	$I_{OH} = -3.2 \text{ mA}, V_{IN} > 250 \text{ mV}$	1.2^{1}			V
Output Low Voltage	V_{OL}	$I_{OL} = +3.2 \text{ mA}, V_{IN} > 250 \text{ mV}$	100 L) Y .	0.3	V
POWER SUPPLY		W. 100Y.CO. TITW W				
Power Supply Rejection Ratio	PSRR	$+2.7 \text{ V} \le \text{V}_{\text{CC}}, \text{V}_{\text{EE}} \le +6 \text{ V}$		40		dB
Supply Currents		$V_0 = 0 \text{ V}, R_L = \infty$				· «1
V+ Supply Current	I+	N TY		4.0	4.5	mA
1, 100 COM'1.		$-40^{\circ}\text{C} \le \text{T}_{\text{A}} \le +85^{\circ}\text{C}$			5.5	mA
Ground Supply Current	I_{GND}	100x.		1.6	2.5	mA
M. COM		$-40^{\circ}\text{C} \le \text{T}_{\text{A}} \le +85^{\circ}\text{C}$			3.0	mA
V– Supply Current	I–	COM. In		2.4	3.3	mA
MM 1007.CO	TW	-40 °C $\leq T_A \leq +85$ °C	M.	W 10	3.8	mA
DYNAMIC PERFORMANCE		WWW. 100Y. CO. TITW				MT
Propagation Delay	$t_{ m P}$	100 mV Step with 20 mV Overdrive ²		8.5	9.8	ns

MOTES

Specifications subject to change without notice.

ABSOLUTE MAXIMUM RATINGS

Total Analog Supply Voltage +14 V
Digital Supply Voltage
Analog Positive Supply-Digital Positive Supply600 mV
Input Voltage ¹ ±7 V
Differential Input Voltage ±8 V
Output Short-Circuit Duration to GND Indefinite
Storage Temperature Range
N, R, RU Package65°C to +150°C
Operating Temperature Range40°C to +85°C
Junction Temperature Range
N, R, RU Package65°C to +150°C
Lead Temperature Range (Soldering, 10 sec)+300°C

Package Type	θ_{JA}^2	$\theta_{ m JC}$	Units
8-Lead Plastic DIP (N)	103	43	°C/W
8-Lead SO (R)	158	43	°C/W
8-Lead TSSOP	240	43	°C/W

NOTES

 1 The analog input voltage is equal to ± 7 V or the analog supply voltage, whichever is less.

 $^2\theta_{JA}$ is specified for the worst case conditions, i.e., θ_{JA} is specified for device in socket for P-DIP and θ_{JA} is specified for device soldered in circuit board for SOIC and TSSOP packages.

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ORDERING GUIDE

Model	Temperature Range	Package Description	Package Options
AD8561AN	−40°C to +85°C	8-Lead Plastic DIP	N-8
AD8561ARU	−40°C to +85°C	8-Lead Thin Shrink Small Outline	RU-8
AD8561AR	−40°C to +85°C	8-Lead Small Outline IC	SO-8

CAUTION.

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the AD8561 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



Output high voltage without pull-up resistor. It may be useful to have a pull-up resistor to V+ for 3 V operation.

²Guaranteed by design.

Typical Performance Characteristics (V+=+5 V, V-=0 V, $T_A=+25$ °C unless otherwise noted)

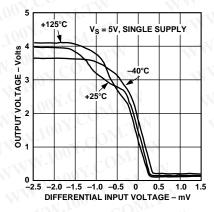


Figure 1. Output Voltage vs. Differential Input Voltage

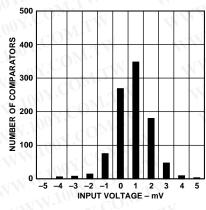


Figure 2. Typical Distribution of Input Offset Voltage

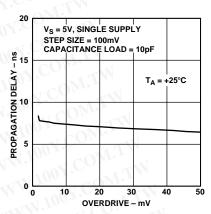


Figure 3. Propagation Delay vs. Overdrive

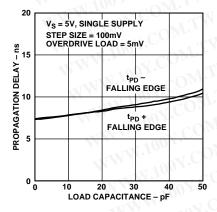


Figure 4. Propagation Delay vs. Load Capacitance

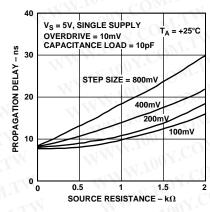


Figure 5. Propagation Delay vs. Source Resistance

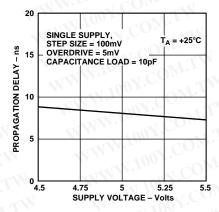


Figure 6. Propagation Delay vs. Positive Supply Voltage

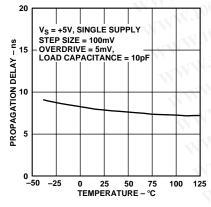


Figure 7. Propagation Delay vs. Temperature

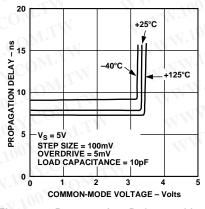


Figure 8. Propagation Delay vs. V_{CM}

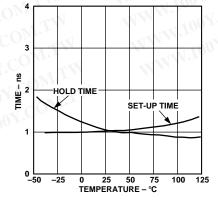


Figure 9. Latch Setup-and-Hold Time vs. Temperature

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AD8561

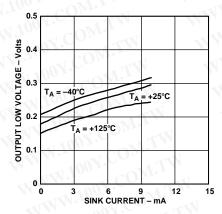


Figure 10. Output Low Voltage, V_{OL} vs. Sink Current

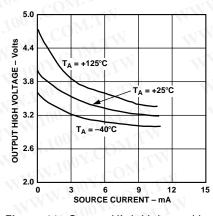


Figure 11. Output High Voltage, $V_{\rm OH}$ vs. Source Current

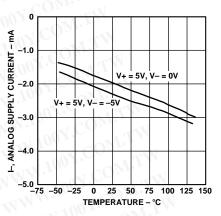


Figure 12. Analog Supply Current vs. Temperature for +5 V, -5 V Supplies

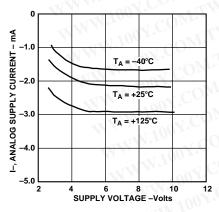


Figure 13. Analog Supply Current vs. Supply Voltage for +5 V, -5 V Supplies

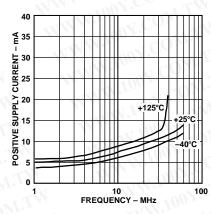


Figure 14. Positive Supply Current vs. Frequency

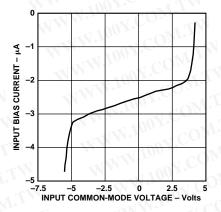


Figure 15. Input Bias Current vs. Input Common-Mode Voltage for +5 V, –5 V Supplies

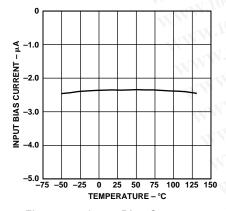


Figure 16. Input Bias Current vs. Temperature

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APPLICATIONS

OPTIMIZING HIGH SPEED PERFORMANCE

As with any high speed comparator or amplifier, proper design and layout techniques should be used to ensure optimal performance from the AD8561. The performance limits of high speed circuitry can easily be a result of stray capacitance, improper ground impedance or other layout issues.

Minimizing resistance from source to the input is an important consideration in maximizing the high speed operation of the AD8561. Source resistance in combination with equivalent input capacitance could cause a lagged response at the input, thus delaying the output. The input capacitance of the AD8561 in combination with stray capacitance from an input pin to ground could result in several picofarads of equivalent capacitance. A combination of 3 k Ω source resistance and 5 pF of input capacitance yields a time constant of 15 ns, which is slower than the 5 ns capability of the AD8561. Source impedances should be less than 1 k Ω for the best performance.

It is also important to provide bypass capacitors for the power supply in a high speed application. A 1 μ F electrolytic bypass capacitor should be placed within 0.5 inches of each power supply pin, Pin 1 and Pin 4, to ground. These capacitors will reduce any potential voltage ripples from the power supply. In addition, a 10 nF ceramic capacitor should be placed as close as possible from the power supply pins to ground. These capacitors act as a charge reservoir for the device during high frequency switching.

A ground plane is recommended for proper high speed performance. This can be created by using a continuous conductive plane over the surface of the circuit board, only allowing breaks in the plane for necessary current paths. The ground plane provides a low inductive ground, eliminating any potential differences at different ground points throughout the circuit board caused from "ground bounce." A proper ground plane also minimizes the effects of stray capacitance on the circuit board.

REPLACING THE LT1016

The AD8561 is pin compatible with the LT1016 comparator. While it is easy to replace the LT1016 with the higher performance AD8561, please note that there are differences, and it is useful to check these to ensure proper operation.

There are five major differences between the AD8561 and the LT1016—input voltage range, input bias currents, speed, output swing and power consumption.

When operated on a +5 V single supply, the LT1016 has an input voltage range from +1.25 V to +3.5 V. The AD8561 has a wider input range from 0 V to 3.0 V. Signals above 3.0 V may result in slower response times (see Figure 8). If both signals exceed 3.0 V, the signals may be shifted or attenuated to bring them into range, keeping in mind the note about source resistance in Optimizing High Speed Performance. If only one of the signals exceeds 3.0 V only slightly, and the other signal is always well within the 0 V to 3 V range, the comparator may operate without changes to the circuit.

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Note that signals much greater than 3.0 V will result increased input currents and may cause the device to operate more slowly.

The input bias current of the AD8561 is lower ($-3\,\mu\text{A}$ typical) than the LT1016 (+5 μA typical), and the current flows out of the AD8561 and into LT1016. If relatively low value resistors and/or low impedance sources are used on the inputs, the voltage shift due to bias current should be small.

The AD8561 (6.75 ns typical) is faster than the LT1016 (10 ns typical). While this is beneficial to many systems, timing may need to be adjusted to take advantage of the higher speed.

The AD8561 has slightly more output voltage swing, from 0.2 V above ground to within 1.1 V of the positive supply voltage.

The AD8561 uses less current (typically 5 mA) than the LT1016 (typically 25 mA).

INCREASING OUTPUT SWING

Although not required for normal operation, the output voltage swing of the AD8561 can be increased by connecting a 5 k Ω resistor from the output of the device to the V+ power supply. This configuration can be useful in low voltage power supply applications where maximizing output voltage swing is important. Adding a 5 k Ω pull-up resistor to the device's output will not adversely affect the specifications of the AD8561.

OUTPUT LOADING CONSIDERATIONS

The AD8561 output can deliver up to 40 mA of output current without any significant increase in propagation delay. The output of the device should not be connected to more than twenty (20) TTL input logic gates, or drive a load resistance less than $100~\Omega$.

To ensure the best performance from the AD8561 it is important to minimize capacitive loading of the output of the device. Capacitive loads greater than 50 pF will cause ringing on the output waveform and will reduce the operating bandwidth of the comparator.

SETUP AND HOLD TIMES FOR LATCHING THE OUTPUT

The latch input, Pin 5, can be used to retain data at the output of the AD8561. When the voltage at the latch input goes high, the output of the device will remain constant regardless of the input voltages. The setup time for the latch is 2 ns-3 ns and the hold time is 3 ns. This means that to ensure data retention at the output, the input signal must be valid at least 5 ns before the latch pin goes high and must remain valid at least 3 ns after the latch pin goes high. Once the latch input voltage goes low, new output data will appear in approximately 8 ns.

A logic high for the latch input is a minimum of +2.0 V and a logic low is a maximum of +0.8 V. This makes the latch input easily interface with TTL or CMOS logic gates. The latch circuitry in the AD8561 has no built-in hysteresis.

AD8561

INPUT STAGE AND BIAS CURRENTS

The AD8561 uses a PNP differential input stage that enables the input common-mode range to extend all the way from the negative supply rail to within 2.2 V of the positive supply rail. The input common-mode voltage can be found as the average of the voltage at the two inputs of the device. To ensure the fastest response time, care should be taken not to allow the input common-mode voltage to exceed either of these voltages.

The input bias current for the AD8561 is $3 \,\mu A$. As with any PNP differential input stage, this bias current will go to zero on an input that is high and will double on an input that is low. Care should be taken in choosing resistor values to be connected to the inputs as large resistors could cause significant voltage drops due to the input bias current.

The input capacitance for the AD8561 is typically 3 pF. This is measured by inserting a 5 k Ω source resistance to the input and measuring the change in propagation delay.

USING HYSTERESIS

Hysteresis can easily be added to a comparator through the addition of positive feedback. Adding hysteresis to a comparator offers an advantage in noisy environments where it is not desirable for the output to toggle between states when the input signal is near the switching threshold. Figure 17 shows a method for configuring the AD8561 with hysteresis.

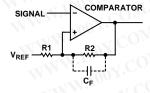


Figure 17. Configuring the AD8561 with Hysteresis

The input signal is connected directly to the noninverting input of the comparator. The output is fed back to the inverting input through R1 and R2. The ratio of R1 to R1 + R2 establishes the width of the hysteresis window with V_{REF} setting the center of the window, or the average switching voltage. The Q output will switch high when the input voltage is greater than V_{HI} and will not switch low again until the input voltage is less than V_{LO} as given in Equation 1:

$$\begin{split} V_{HI} = & \left(V_+ - 1 - V_{REF} \right) \frac{R1}{R1 + R2} + V_{REF} \\ V_{LO} = & V_{REF} \left(1 - \frac{R1}{R1 + R2} \right) \end{split} \tag{1}$$

Where V_{+} is the positive supply voltage.

The capacitor C_F can also be added to introduce a pole into the feedback network. This has the effect of increasing the amount of hysteresis at high frequencies. This can be useful when comparing a relatively slow signal in a high frequency noise environ-

ment. At frequencies greater than $f_{\rm P} = \frac{1}{2\pi\,C_FR^2}$, the hysteresis window approaches $V_{\rm HI} = V_+ - 1$ V and $V_{\rm LO} = 0$ V. At frequencies less than $f_{\rm P}$ the threshold voltages remain as in Equation 1.

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SPICE Model

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```
* AD8561 SPICE Macro-Model Typical Values
* 4/98, Ver. 1.0
* TAM / ADSC
               non-inverting input
* Node assignments
                       inverting input
WW.100Y.COM.
                           positive supply
                                      negative supply
                                            Latch
                               WWW.100Y.COM80W
                              50
.SUBCKT AD8561
                                WWW.100Y.COM.TW
 INPUT STAGE
        2 5 PIX
Q1
IBIAS 99 5 800E-6
RC1 4 50 1E2
              100Y.COM.TW
        _ы-12
2 3E-12
7 1
RC2
      6 50 1E3
CL1
CIN
      1
        7 1
VCM1
    99
D1
      5
         7 DX
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EOS
         1 POLY(1) (31,98) 1E-3 1
                                          WWW.100Y.COM.TW
* Reference Voltage
EREF 98 0 POLY(2) (99,0) (50,0) 0 0.5 0.5
RREF 98 0 100E3
* CMRR=80dB, ZERO AT 1kHz
ECM1 30 98 POLY(2) (1,98) (2,98) 0 0.5 0.5
                    WWW.100Y.COM.
RCM1 30 31 10E3
RCM2 31 98 1
CCM1 30 31 15.9E-9
 Latch Section
RX 80 51 100E3
E1 10 98 (4,6) 1
S1 10 11 (80,51) SLATCH1
R2 11 12 1
C3 12 98 10E-12
E2 13 98 (12,98) 1
R3 12 13 500
* Power Supply Section
```

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```
GSY2 52 50 POLY(1) (99,50) 3.7E-3 -.6E-3
RSY 52 51 10
GSY1 99 52 POLY(1) (99,50) 4E-3 -2.6E-4
* Gain Stage Av=250 fp=100MHz
*
G2 98 20 (10
                            WWW.100Y.COM.TW
                            WWW.100Y.COM.TW
G2 98 20 (12,98) 0.25
R1 20 98 1000
C1 20 98 10E-13
D2 20 21 DX
D3 22 20 DX
V1 99 21 DC 0.8
V2 22 50 DC 0.8
             ON.COM.TW
  Q Output
Q3 99 41 46 NOX
                OOY.COM.TW
Q4 47 42 50 NOX
_ ±0 42 5E3
CB1 99 41 10E-12
CB2 42 50 5F
RO1 46 45 2E3
RO2 47 45 500
EO1 98 43 POLY(1) (20,98) 0 1
                 WW.100Y.COM.TW
EO2 40 98 POLY(1) (20,98) 0 1
99 61 66 NOX
Q6 67 62 50 NOX
RB3 63 61 200
RB4 60 62 5E3
                   WWW.100Y.COM.TW
CB3 99 61 10E-12
                            100Y.COM.TW
CB4 62 50 5E-12
RO3 66 65 2E3
20 98 POLY(1) (20,98) 0 1
EO4 98 60 POLY(1) (20,98) 0 1
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                        WWW.100Y.COM.TW
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* MODELS
.MODEL NOX NPN(BF=100,VAF=130,IS=1E-14)
.MODEL DX D(IS=1F-16)
.MODEL SLATCH1 VSWITCH(ROFF=1E6,RON=500,VOFF=2.1,VON=1.4)
                              WWW.100Y.C
.ENDS AD8561
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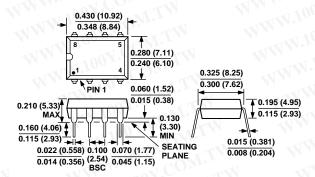
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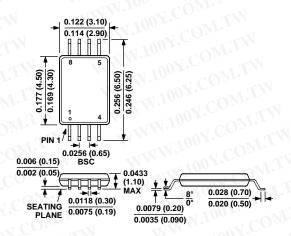
OUTLINE DIMENSIONS

Dimensions shown in inches and (mm).

8-Lead Plastic DIP (N-8)

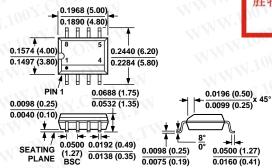


8-Lead Thin Shrink Small Outline (RU-8)



8-Lead Small Outline IC (SO-8)





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